

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of

MANABE et al.

Group Art Unit: 2811

Divisional of

Appln. No.: 09/417,778

Examiner: Tran, M.

Filed: Herewith

Title: LIGHT EMITTING SEMICONDUCTOR

DEVICE USING GALLIUM NITRIDE GROUP COMPOUND

October 2, 2000

PRELIMINARY AMENDMENT

Honorable Commissioner of Patents and Trademarks, Washington, DC 20231

Sir:

Kindly enter the following preliminary amendments.

IN THE TITLE:

Please change the title to A METHOD FOR MANUFACTURING A GALLIUM NITRIDE GROUP COMPOUND SEMICONDUCTOR ...

IN THE CLAIMS:

Please cancel claim 1 and add the attached new claims 19-118.

--19. A method for producing a gallium nitride group compound semiconductor by using an organometallic compound vapor phase epitaxy, comprising the steps of: